**GH6D407B5A Hologram Lasers** 

# **GH6D407B5A**

#### **Features**

- (1) With built-in high speed response OPIC\* (MIN. 60MHz)
- (2) For ×10 speed DVD-ROM drives
- (3) Thin package (3.0mm thickness) due to insert frame
- (4) Built-in RF amp enables low reflective disc reading (DVD-R, DVD-RW).
- (5) With built-in beam splitter and diffraction grating \*OPIC: (Optical IC) is a trademark of SHARP Corporation. An OPIC consists of a light-detecting element and a signal-processing circuit integrated onto a single chip.

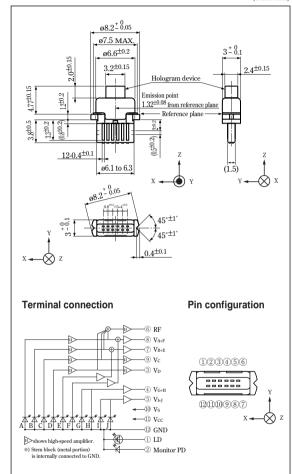
# **Applications**

- (1) DVD-ROM drives
- (2) DVD-ROM drives for notebook PCs

# 3mm Thickness Resin type Red Hologram Laser for X10 Speed DVD-ROM Drive

#### **Outline Dimensions**

(Unit:mm)



## **Absolute Maximum Ratings**

(	1c=25 C)
	Unit

Param	eter	Symbol	Rating	Unit
*1 Optical power outp	Рн	6.3	mW	
Reverse voltage	Laser	37	2	V
	Monitor photodiode	$V_R$	30	V
OPIC supply voltag	Vcc	6	V	
*2 Operating tempera	Topr	-10 to +70	°C	
*2 Storage temperatur	Tstg	-40 to +85	°C	
*3 Soldering temperat	Tsold	260	°C	

<sup>\*1</sup> Output power from hologram laser, CW (Continuous Wave) drive

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Case temperature

At the position of 1.6mm from the lead base (Within 5s)

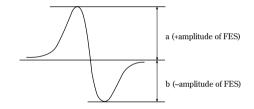
## **■** Electro-optical Characteristics

(Vcc=5V, Vs=1/2Vcc, Tc=25°C)

-						
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
*1 Focal offset	DEF	V <sub>RF</sub> =1.0V	-0.5	-	+0.5	μm
*2 Focal error symmetry	Bres	$V_{RF}=1.0V$	-25	-	+25	%
*3 Radial error balance	Bres	P <sub>H</sub> =4.75mW	-25	-	+25	%
*4 RF output amplitude	Vrf	P <sub>H</sub> =4.75mW	0.75	1.05	1.35	V
*5 FES output amplitude	VFES	Vrf=1.0V	0.51	0.66	0.83	V
*6 Main spot balance	MSB	P <sub>H</sub> =4.75mW	75	(100)	125	%
*7 Radial spot balance	RSB	P <sub>H</sub> =4.75mW	75	(100)	125	%
Jitter	JIT	Vrf=1.0V	-	-	12	%
Threshold current	Ith	-	-	27	35	mA
Operating current	Iop	P <sub>H</sub> =4.75mW	-	36	49	mA
Operating voltage	$V_{op}$	P <sub>H</sub> =4.75mW	-	2.2	2.7	V
Wavelength	$\lambda_{ m p}$	P <sub>H</sub> =4.75mW	640	654	660	nm
Output current	Im	P <sub>H</sub> =4.75mW, V <sub>R</sub> =15V	0.06	(0.18)	0.3	mA
Differential efficiency	ηα	3.8mW I(4.75mW)-I(0.95mW)	0.35	0.55	0.84	mW/mA

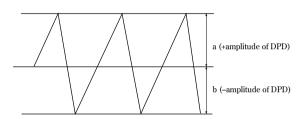
<sup>\*1</sup> Distance between FES=0 and jitter minimum point

Notice

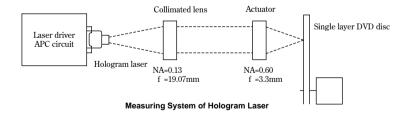


\*3 DPD signal

$$\frac{\text{a-b}}{2\times(\text{a+b})}$$



- \*4 Amplitude of VA+VB+VC+VD (focal servo ON, radial servo ON)
- \*5 VA+F-VB+E (Focal vibration)
- \*\*6 (VA+F+VB+E) / (VC+VD) (focal servo ON, radial servo OFF)
- \*7 Vc / VD (focal servo ON, radial servo OFF)



<sup>\*2 (</sup>a-b) / (a+b)

# ■ Electro-optical Characteristics of Laser Diode (Design Standard\*)

(Tc=25°C)

Para	meter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Half intensity one	Par		θ//	D- 2W	7	8.5	11	۰
Half intensity angle		Perpendicular	θΤ		25	30	35	۰
Emission	Deviation	Parallel	ø//	Po=3mW	-2.1	0	+2.1	٠
characteristics	angle	Perpendicular	ø⊥		-3	0	+3	٠
Misalignment position		Δx	_	-80	-	+80	μm	
		Δy		-80	-	+80	μm	
		$\Delta z$		-80	-	+80	μm	
*6 Interference patte	ern intensity	у	α	Po=3mW	-	-	1	-

# ■ Electrical Characteristics of Monitor Photodiode (Design Standard\*)

(Tc=25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
*1 Sensitivity	S		-	0.032	-	mA/mW
Dark current	ID	V <sub>R</sub> =15V	-	-	1	nA
Terminal capacitance	Ct		-	8.5	-	pF

<sup>\*1</sup> For hologram output power

## ■ Electro-optical Characteristics of OPIC for Signal Detection (Design Standard\*)

(Tc=25°C, Vcc=5V, Vs=2.5V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit	*2 Segment
Supply voltage	Vcc	-	4.5	5.0	5.5	V	-
Reference voltage	Vs	ı	2.0	2.5	2.63	V	-
Supply current	Icc	-	10	17	24	mA	-
*3,4 Output off-set voltage	V <sub>OD1</sub>		-30	-	+30	mV	Vaf, Vbe, Vc, Vd, Vgh, Vij
	$V_{\mathrm{OD2}}$	No light	1.2	1.36	1.52	V	V <sub>RF</sub>
Off-set voltage difference	$\Delta V_{\mathrm{OD1}}$		-25	-	+25	mV	VAF-VBE, VC-VD
	$\Delta V_{\mathrm{OD2}}$		-30	-	+30	mV	V <sub>GH</sub> -V <sub>IJ</sub>
	fcF1		1	5	-	MHz	Vaf, Vbe, Vgh, Vij
*5 Response frequency	fcF2	-3dB	60	90	-	MHz	Vc, VD
	fcF3		60	90	-	MHz	V <sub>RF</sub>
Peaking level	$V_{PK}$	f=1 to 36MHz	-2	-	+2	dB	Vrf
Group delay	tgd	f=1 to 36MHz	-	5	10	ns	Vc, Vd, Vrf
Noise level	$V_{mP}$	f=36MHz, BW=30kHz	-	-74	-	dBm	$V_{RF}$

<sup>\*2</sup> Applicable divisions correspond to output terminals

G C H E A B F I D

Segment No.	Output
A + F	Vaf
B + E	Vbe
C	Vc
D	V <sub>D</sub>
G + H	V <sub>GH</sub>
I + J	V <sub>IJ</sub>

<sup>\*\*</sup> Output amplitude=0dB (input signal 1MHz) Load resistance R<sub>L</sub>=10k $\Omega$ , load capacitance C<sub>L</sub>=10pF (For V<sub>RF</sub>, load capacitance C<sub>L</sub>=10pF)

\*6 Noise solution against feed-back light (Radio frequency modulation circuit) is required.

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<sup>\*3</sup> Difference from Vs

<sup>\*4</sup> Difference from GND

<sup>\*</sup> These parameters are not guaranteed performance, but general specifications of each optical element which makes up a hologram laser.

<sup>•</sup> Please refer to the chapter "Handling Precautions"

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